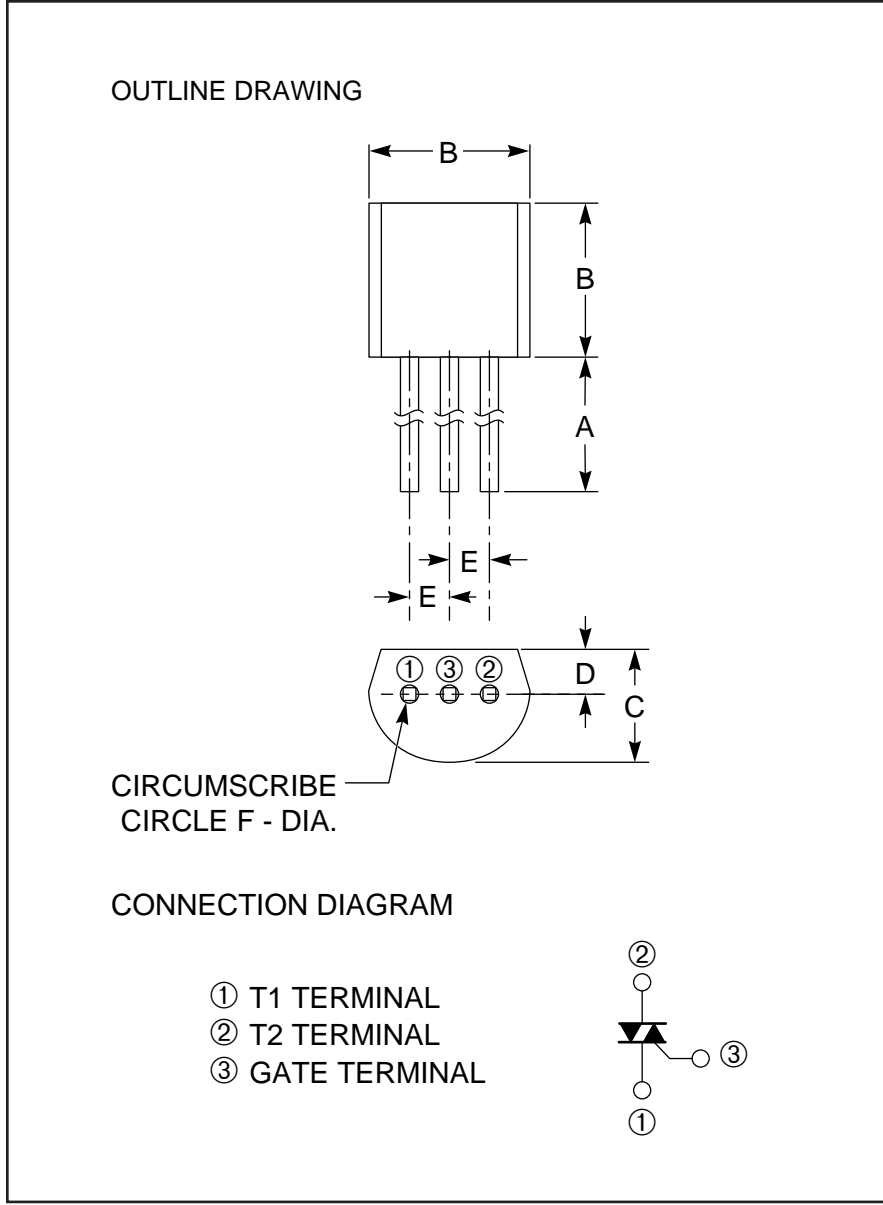
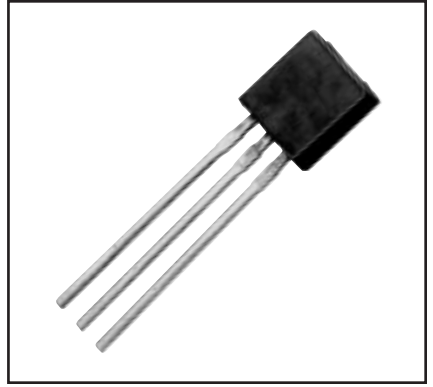


### Lead-Mount Triac 1 Ampere/400-600 Volts



Outline Drawing (Conforms to JEDEC TO-92)

Dimensions	Inches	Millimeters
A	0.45 Min.	12.5 Min.
B	0.20 Max.	5.0 Max.
C	0.15 Max.	3.9 Max.
D	0.05	1.3
E	0.05	1.25
F	0.028 Dia.	0.7 Dia.



**Description:**

A triac is a solid state silicon AC switch which may be gate triggered from an off-state to an on-state for either polarity of applied voltage.

**Features:**

- Glass Passivation

**Applications:**

- AC Switch

**Ordering Information:**

Example: Select the complete seven or eight digit part number you desire from the table - i.e. BCR1AM-8 is a 400 Volt, 1 Ampere Triac.

Type	V <sub>DRM</sub> Volts	Code
BCR1AM	400	-8
	600	-12

## BCR1AM

### Lead-Mount Triac

1 Ampere/400-600 Volts

### Absolute Maximum Ratings, $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	BCR1AM-8	BCR1AM-12	Units
Repetitive Peak Off-state Voltage (Gate Open)	$V_{DRM}$	400	600	Volts
Non-repetitive Peak Off-state Voltage (Gate Open)	$V_{DSM}$	500	720	Volts
On-state Current, $T_a = 56^\circ\text{C}$	$I_{T(RMS)}$	1	1	Amperes
Non-repetitive Peak Surge, One Cycle (60 Hz)	$I_{TSM}$	10	10	Amperes
Non-repetitive Peak Surge, One Cycle (50 Hz)	$I_{TSM}$	9.1	9.1	Amperes
$I^2t$ for Fusing, $t = 8.3\text{ msec}$	$I^2t$	0.4	0.4	$\text{A}^2\text{sec}$
Peak Gate Power Dissipation, $20\text{ }\mu\text{sec}$	$P_{GM}$	1	1	Watts
Average Gate Power Dissipation	$P_{G(avg)}$	0.1	0.1	Watts
Peak Gate Current	$I_{GM}$	1	1	Amperes
Peak Gate Voltage	$V_{GM}$	6	6	Volts
Storage Temperature	$T_{stg}$	-40 to 125	-40 to 125	$^\circ\text{C}$
Operating Temperature	$T_j$	-40 to 125	-40 to 125	$^\circ\text{C}$
Weight	-	0.23	0.23	Grams

### Electrical and Thermal Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics*	Symbol	Test Conditions (Trigger Mode)				BCR1AM			Units
		$V_D$	$R_L$	$R_G$	$T_j$	Min.	Typ.	Max.	
Gate – Parameters									
DC Gate Trigger Current									
MT2+ Gate+	$I_{GT}$	6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	5	mA
MT2+ Gate-		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	5	mA
MT2- Gate-		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	5	mA
MT2- Gate+		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	10	mA
DC Gate Trigger Voltage									
MT2+ Gate+	$V_{GT}$	6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	2	Volts
MT2+ Gate-		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	2	Volts
MT2- Gate-		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	2	Volts
MT2- Gate+		6V	$6\Omega$	$330\Omega$	$25^\circ\text{C}$	-	-	2	Volts
DC Gate Non-trigger Voltage									
All	$V_{GD}$	$1/2 V_{DRM}$	-	-	$125^\circ\text{C}$	0.1	-	-	Volts

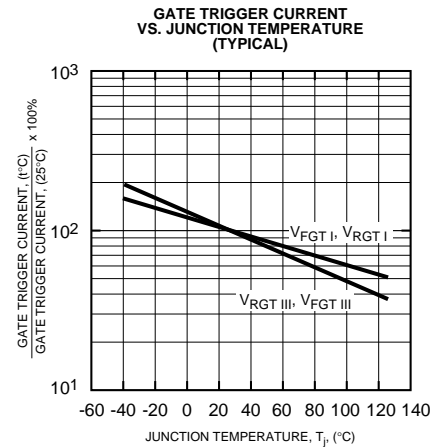
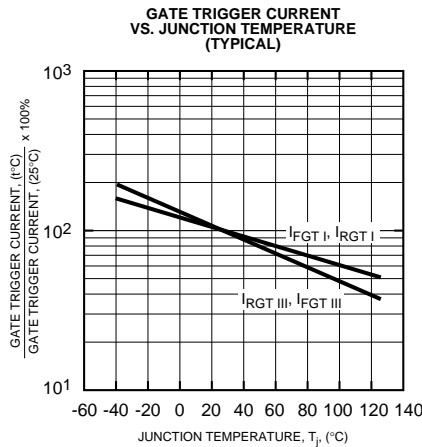
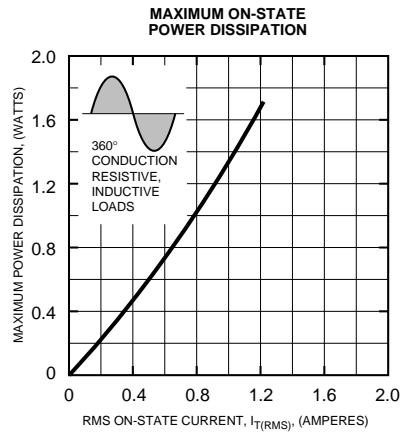
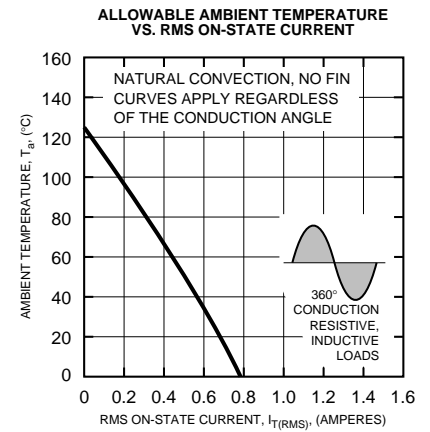
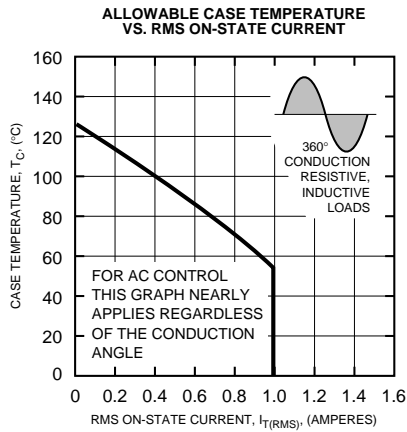
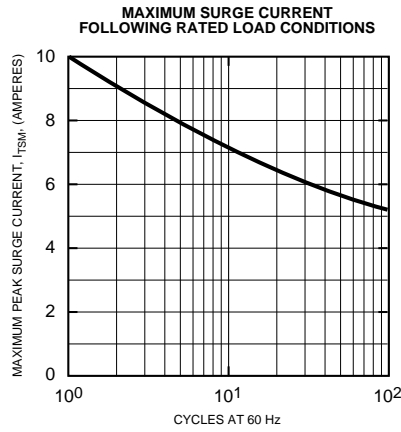
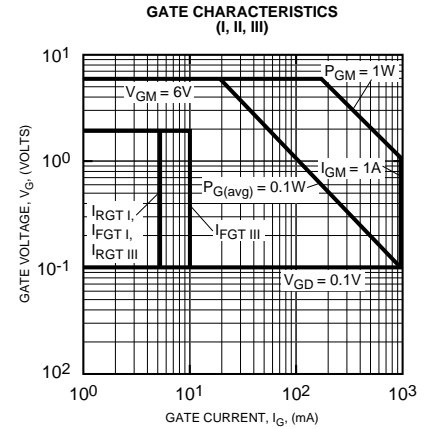
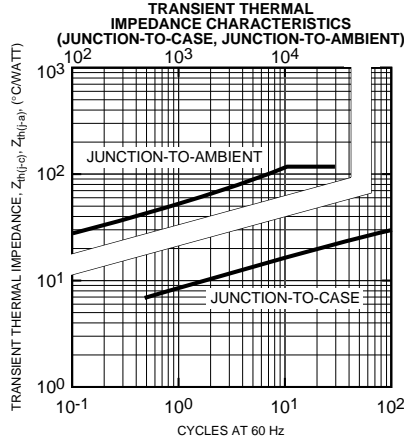
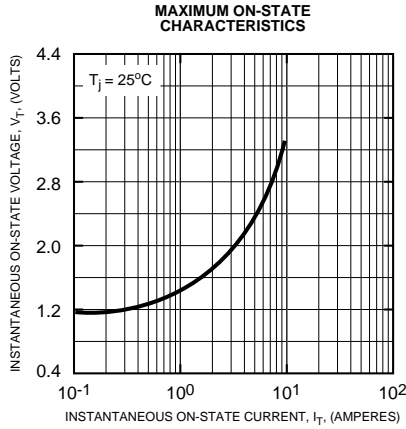
\*Characteristic values apply for either polarity of Main Terminal 2 referenced to Main Terminal 1.

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-case	$R_{th(j-c)}$	-	-	-	50	$^\circ\text{C}/\text{W}$
Steady State Thermal Resistance, Junction-to-ambient	$R_{th(j-a)}$	-	-	-	120	$^\circ\text{C}/\text{W}$
Voltage – Blocking State Repetitive Off-state Current	$I_{DRM}$	Gate Open Circuited, $V_D = V_{DRM}$ , $T_j = 125^\circ\text{C}$	-	-	1	mA
Current – Conducting State Peak On-state Voltage	$V_{TM}$	$T_c = 25^\circ\text{C}$ , 8.3ms Pulsewidth Duty Cycle <2%, $I_{TM} = 1.5\text{A}$	-	-	1.6	Volts
Critical Rate-of-Rise of Commutating Off-state Voltage (Commutating dv/dt) ▲ (Switching)	$(dv/dt)_c$	-	-	-	-	$\text{V}/\mu\text{s}$

## BCR1AM

### Lead-Mount Triac

1 Ampere/400-600 Volts

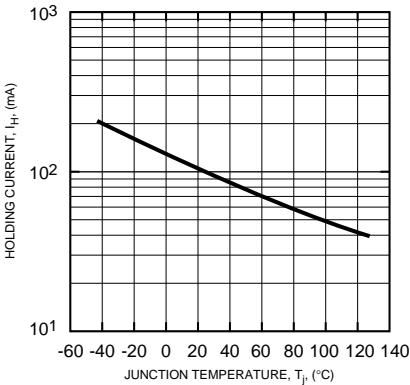


## BCR1AM

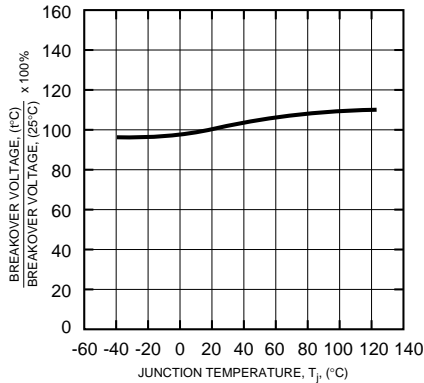
### Lead-Mount Triac

1 Ampere/400-600 Volts

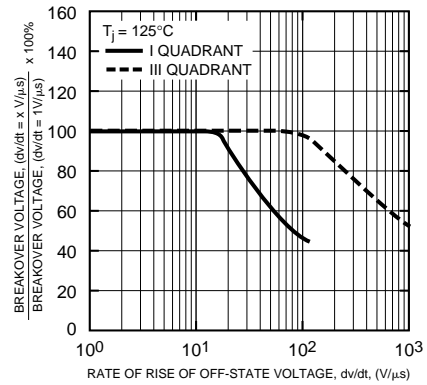
**HOLDING CURRENT VS. JUNCTION TEMPERATURE (TYPICAL)**



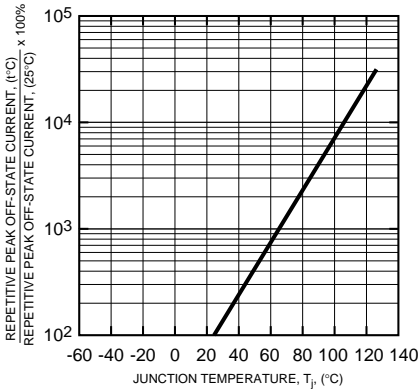
**BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE (TYPICAL)**



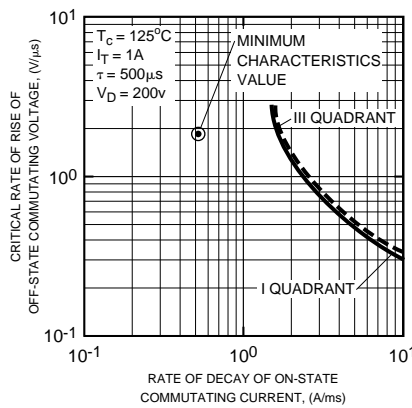
**BREAKOVER VOLTAGE VS. RATE OF RISE OF OFF-STATE VOLTAGE (TYPICAL)**



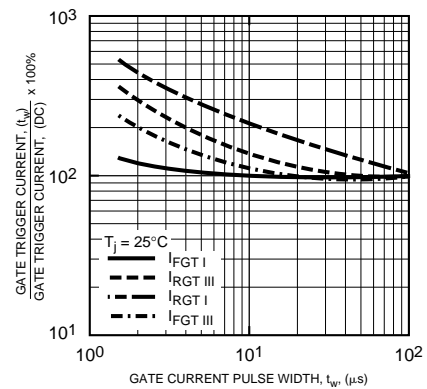
**REPETITIVE PEAK OFF-STATE CURRENT VS. JUNCTION TEMPERATURE (TYPICAL)**



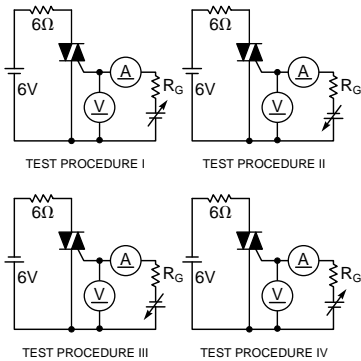
**COMMUTATION CHARACTERISTICS (TYPICAL)**



**GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH (TYPICAL)**



**GATE TRIGGER CHARACTERISTICS TEST CIRCUITS**



Δ Part Number	V <sub>DRM</sub> (Volts)	Commutating dv/dt, (dv/dt) <sub>c</sub> (V/μsec)		Test Condition	Commutating Voltage & Current Waveform (Inductive Load)
		Minimum	Value		
BCR1AM-8	400	2		T <sub>j</sub> = 125°C, Rate of Decay On-state Commutating Current (di/dt) <sub>c</sub> = -0.5A/msec, Peak Off-state Voltage V <sub>D</sub> = 400V	
BCR1AM-12	600	2			